



**ZXTP722MA**

**70V PNP LOW SATURATION TRANSISTOR**

**Features and Benefits**

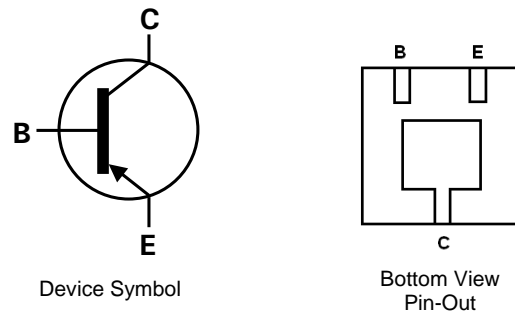
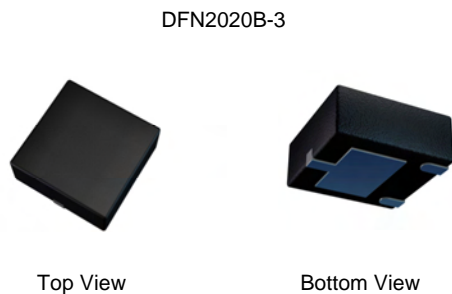
- $BV_{CEO} > -70V$
- $I_C = -2.5A$  Continuous Collector Current
- Low Saturation Voltage (-220mV max @ -1A)
- $R_{SAT} = 117\ m\Omega$  for a low equivalent On-Resistance
- $h_{FE}$  specified up to -3A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- $R_{\theta JA}$  efficient, 60% lower than SOT23
- 4mm<sup>2</sup> footprint, 50% smaller than SOT23
- **Lead-Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free. "Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

- Case: DFN2020B-3
- Case material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal package height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

**Applications**

- MOSFET Gate Driving
- DC-DC Converters
- Charging Circuits
- Power switches
- Motor control

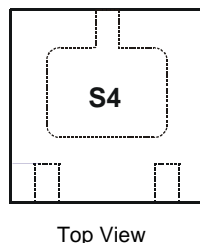


**Ordering Information**

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP722MATA	S4	7	8	3000

- Notes:
1. No purposefully added lead.
  2. Diodes Inc's "Green" policy can be found on our website at <http://www.diodes.com>

**Marking Information**



S4 = Product Type Marking code

**Maximum Ratings** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

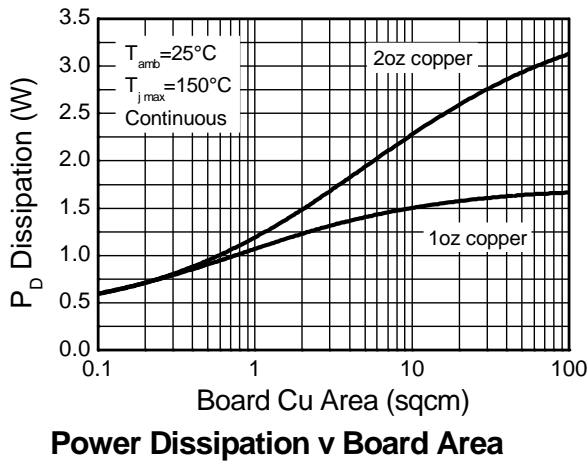
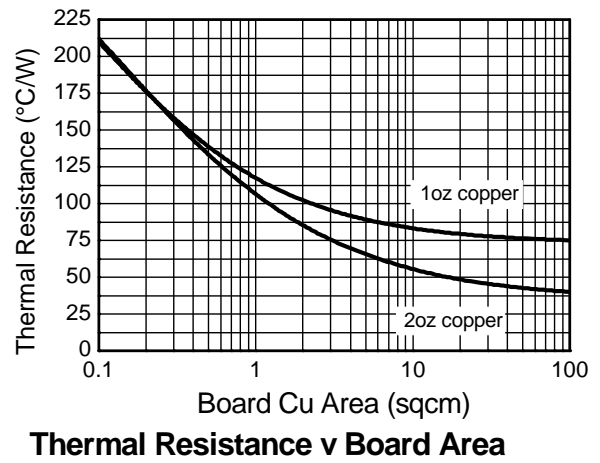
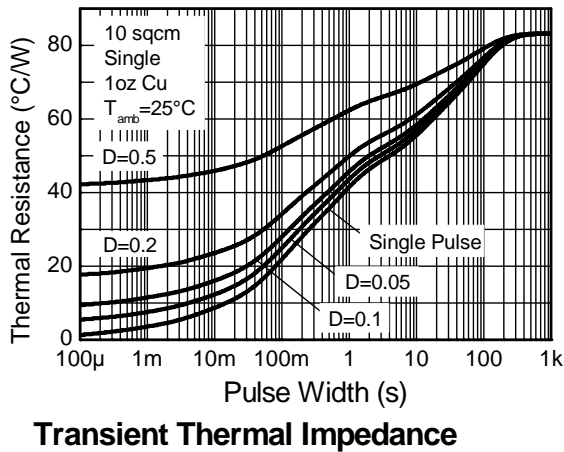
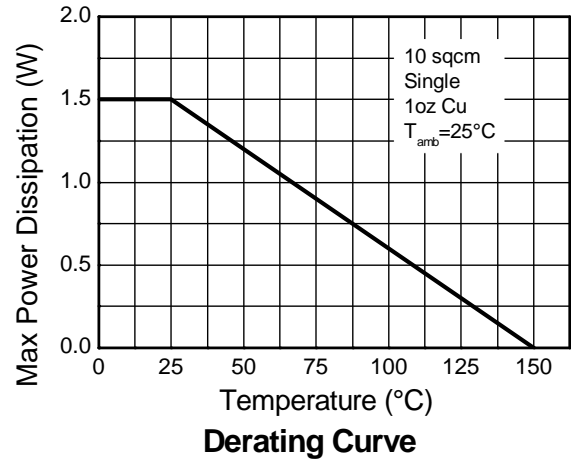
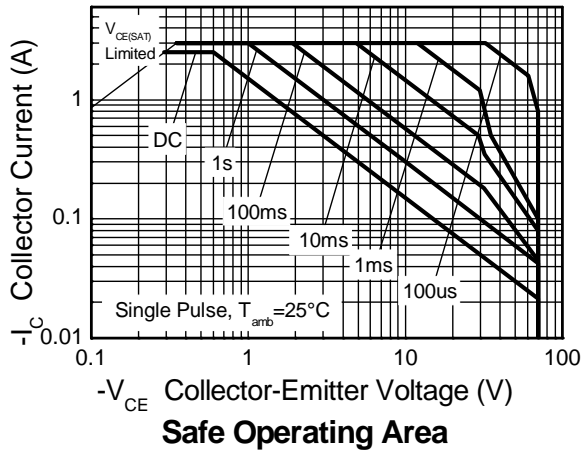
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-70	V
Collector-Emitter Voltage	$V_{CEO}$	-70	
Emitter-Base Voltage	$V_{EBO}$	-7	
Peak Pulse Current	$I_{CM}$	-3	A
Continuous Collector Current	(Note 3)	-2.5	
	(Note 4)	-2.7	
Base Current	$I_B$	-1	

**Thermal Characteristics** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	$P_D$	1.5	W
		12	
		2.45	
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	19.6	$^\circ\text{C}/\text{W}$
		83	
Thermal Resistance, Junction to Lead	$R_{\theta JL}$	51	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

- Notes:
3. For a device surface mounted on 31mm x 31mm (10cm<sup>2</sup>) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
  4. Same as note (3), except the device is measured at  $t \leq 5$  sec.
  5. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).

**Thermal Characteristics**

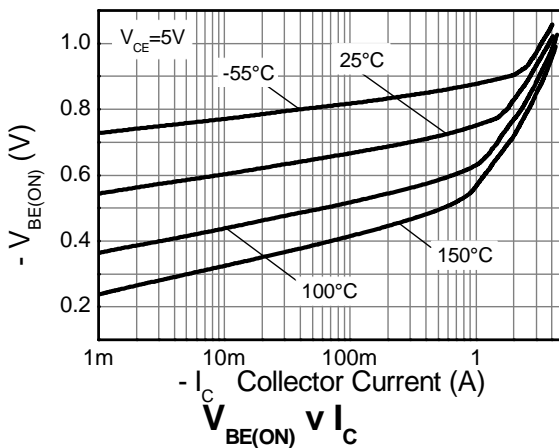
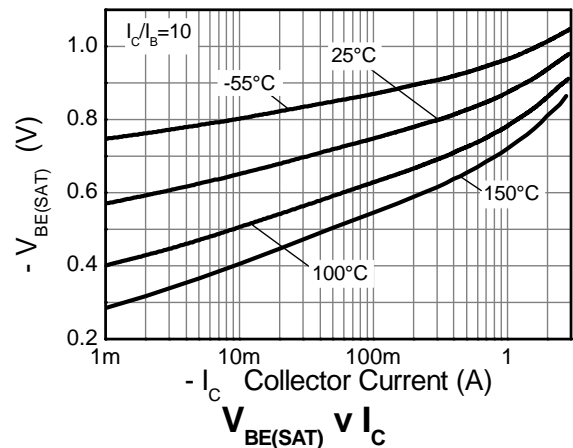
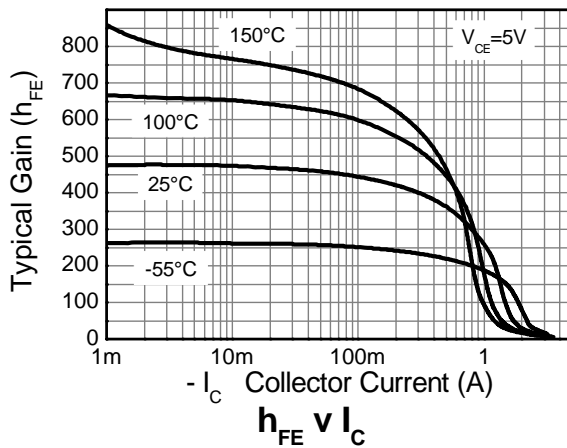
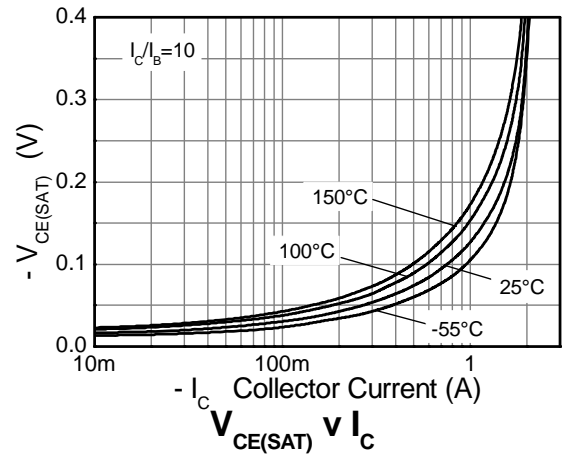
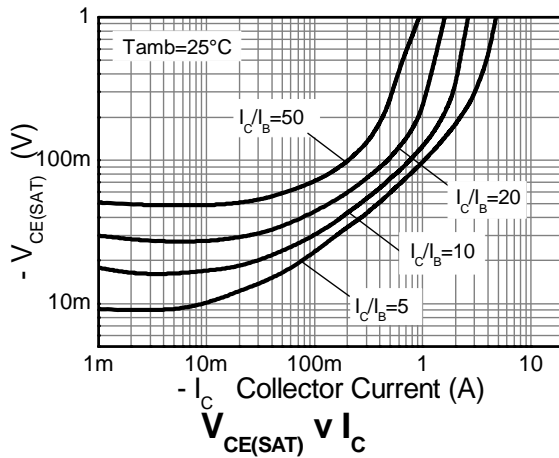


**Electrical Characteristics** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

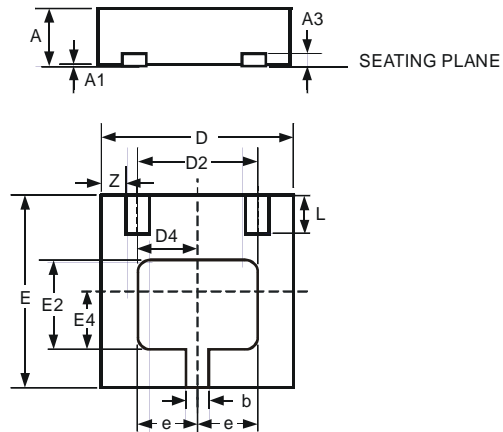
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	-70	-150	-	V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 6)	$BV_{CEO}$	-70	-125	-	V	$I_C = -10\text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	-8.5	-	V	$I_E = -100\mu\text{A}$
Collector Cutoff Current	$I_{CBO}$	-	-	-100	nA	$V_{CB} = -55\text{V}$
Emitter Cutoff Current	$I_{EBO}$	-	-	-100	nA	$V_{EB} = -6\text{V}$
Collector Emitter Cutoff Current	$I_{CES}$	-	-	-100	nA	$V_{CES} = -55\text{V}$
Static Forward Current Transfer Ratio (Note 6)	$h_{FE}$	300	470	-	-	$I_C = -10\text{mA}, V_{CE} = -5\text{V}$
		300	450	-		$I_C = -100\text{mA}, V_{CE} = -5\text{V}$
		175	275	-		$I_C = -1\text{A}, V_{CE} = -5\text{V}$
		40	60	-		$I_C = -1.5\text{A}, V_{CE} = -5\text{V}$
		-	10	-		$I_C = -3\text{A}, V_{CE} = -5\text{V}$
Collector-Emitter Saturation Voltage (Note 6)	$V_{CE(sat)}$	-	-35	-50	mV	$I_C = -0.1\text{A}, I_B = -10\text{mA}$
		-	-135	-200		$I_C = -0.5\text{A}, I_B = -20\text{mA}$
		-	-140	-220		$I_C = -1\text{A}, I_B = -100\text{mA}$
		-	-175	-270		$I_C = -1.5\text{A}, I_B = -200\text{mA}$
Base-Emitter Turn-On Voltage (Note 6)	$V_{BE(on)}$	-	-0.78	-1.00	V	$I_C = -1.5\text{A}, V_{CE} = -5\text{V}$
Base-Emitter Saturation Voltage (Note 6)	$V_{BE(sat)}$	-	-0.94	-1.05	V	$I_C = -1.5\text{A}, I_B = -200\text{mA}$
Output Capacitance	$C_{obo}$	-	14	20	pF	$V_{CB} = -10\text{V}, f = 1\text{MHz}$
Transition Frequency	$f_T$	150	180	-	MHz	$V_{CE} = -10\text{V}, I_C = -50\text{mA}, f = 100\text{MHz}$
Turn-On Time	$t_{on}$	-	40	-	ns	$V_{CC} = -50\text{V}, I_C = -1\text{A}$
Turn-Off Time	$t_{off}$	-	700	-	ns	$I_{B1} = I_{B2} = -50\text{mA}$

Notes: 6. Measured under pulsed conditions. Pulse width  $\leq 300 \mu\text{s}$ . Duty cycle  $\leq 2\%$ .

**Typical Electrical Characteristics**

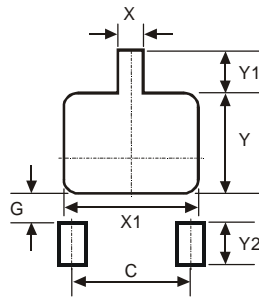


## Package Outline Dimensions



DFN2020B-3			
Dim	Min	Max	Typ
A	0.57	0.63	0.60
A1	0	0.05	0.02
A3	—	—	0.152
b	0.20	0.30	0.25
D	1.95	2.075	2.00
D2	1.22	1.42	1.32
D4	0.56	0.76	0.66
e	—	—	0.65
E	1.95	2.075	2.00
E2	0.79	0.99	0.89
E4	0.48	0.68	0.58
L	0.25	0.35	0.30
Z	—	—	0.225
All Dimensions in mm			

## Suggested Pad Layout



Dimensions	Value (in mm)
C	1.30
G	0.24
X	0.35
X1	1.52
Y	1.09
Y1	0.47
Y2	0.50

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